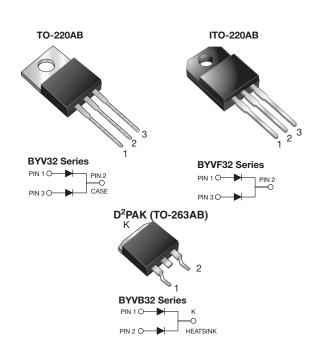


Vishay General Semiconductor

## **Dual Common-Cathode Ultrafast Rectifier**



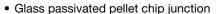
### **DESIGN SUPPORT TOOLS AVAILABLE**



PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	18 A						
V <sub>RRM</sub>	50 V to 200 V						
I <sub>FSM</sub>	150 A						
t <sub>rr</sub>	25 ns						
V <sub>F</sub>	0.85 V						
T <sub>J</sub> max.	150 °C						
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB)						
Circuit configuration	Common cathode						

### **FEATURES**

Power pack





- · Ultrafast recovery time
- · Low switching losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHE3 (for ITO-220AB and D2PAK (TO-263AB package))
- · Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3\_X - RoHS-compliant and AEC-Q101 qualified ("\_X" denotes revision code e.g. A, B,...)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	150	200	V	
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	V	
Maximum DC blocking voltage	$V_{DC}$	50	100	150	200	V	
Maximum average forward rectified current at T <sub>C</sub> = 125 °C	I <sub>F(AV)</sub>	18			Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	150			А		
Operating storage and temperature range	$T_J$ , $T_{STG}$	-65 to +150			°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V <sub>AC</sub>	1500			V		



# BYV32-xxx, BYVF32-xxx, BYVB32-xxx

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CO	NDITIONS	SYMBOL	BYV32-50 BYV32-100 BYV32-150 BYV32-2		BYV32-200	UNIT	
Maximum instantaneous forward	I <sub>F</sub> = 20 A	T <sub>J</sub> = 25 °C	V <sub>E</sub> <sup>(1)</sup> 1.15			V		
voltage per diode	<sub>F</sub> = 5.0 A	T <sub>J</sub> = 100 °C	v <sub>F</sub> ···	0.85		.85	5	
Maximum DC reverse current		T <sub>J</sub> = 25 °C		10				μA
per diode at rated DC blocking voltage		T <sub>J</sub> = 100 °C	I <sub>R</sub>	600				
Maximum reverse recovery time per diode	I <sub>F</sub> = 1 A, V <sub>R</sub> = 3 dI/dt = 100 A/ <sub>1</sub>	30 V us, I <sub>rr</sub> = 10 % I <sub>RM</sub>	t <sub>rr</sub>	25				ns
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	45			pF	

### Note

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER		BYV	BYVF	BYVB	UNIT	
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.6	5.0	1.6	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	BYV32-200-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	BYVF32-200-E3/45	1.97	45	50/tube	Tube			
TO-263AB	BYVB32-200-E3/45	1.35	45	50/tube	Tube			
TO-263AB	BYVB32-200-E3/81	1.35	81	800/reel	Tape and reel			
ITO-220AB	BYVF32-200HE3_A/P (1)	1.97	Р	50/tube	Tube			
TO-263AB	BYVB32-200HE3_A/P (1)	1.35	Р	50/tube	Tube			
TO-263AB	BYVB32-200HE3_A/I (1)	1.35	I	800/reel	Tape and reel			

#### Note

<sup>(1)</sup> AEC-Q101 qualified, available in ITO-220AB and TO-263AB package

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### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

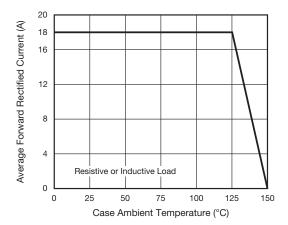


Fig. 1 - Forward Current Derating Curve

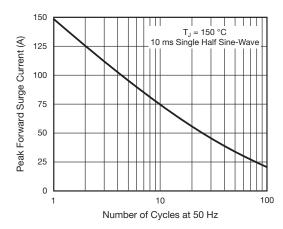


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

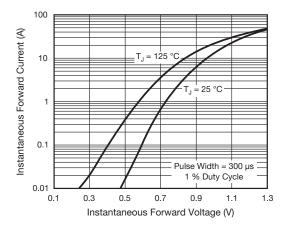


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

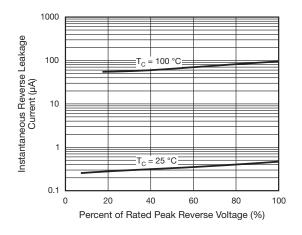


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

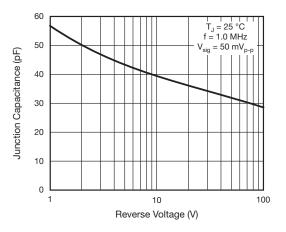
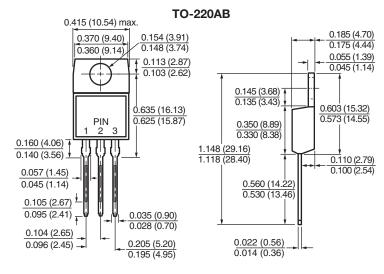


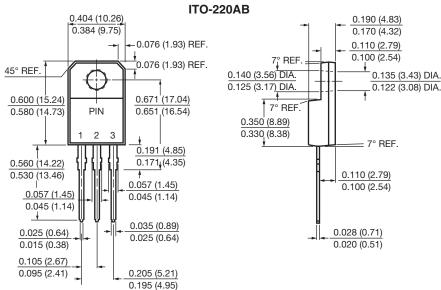
Fig. 5 - Typical Junction Capacitance Per Diode



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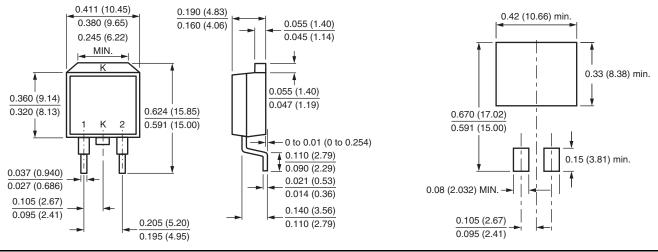
### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





### D<sup>2</sup>PAK (TO-263AB)

### Mounting Pad Layout





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